SLUS566A − JULY 2003 − REVISED NOVEMBER 2003

LEGACY/IEEE802.3af COMPATIBLE POWER INTERFACE SWITCH FOR POWER OVER ETHERNET (PoE) POWERED DEVICES

FEATURES

- **Integrated Power Interface Switch for IEEE 802.3af Powered Devices (PDs)**
- **Precision UVLO Thresholds**
- **20-ms UVLO Off-Time Delay**
- **Provides PD Detection Signature**
- **Provides PD Classification Signature (Class 0−4)**
- **Programmable Inrush Current Limit**
- **Internal 0.3-Ω Low-Side FET**
- **Interfaces to DC/DC Soft-Start for DC/DC Enable**
- **Internal Thermal Protection – Disconnects PD Load**
- **8-Pin SOIC, 8-Pin TSSOP Packages**

APPLICATIONS

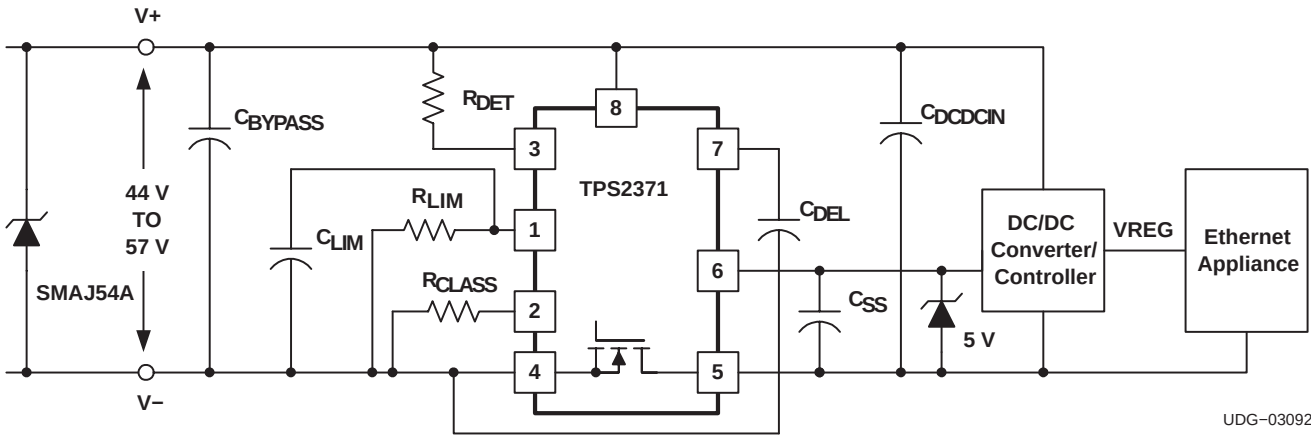
- **VoIP Phones**
- **Internet Appliances**
- **Wireless LAN Access Points**
- **Bluetooth™ Access Points**

DESCRIPTION

Acting as an interface between the Power Source Equipment (PSE) and the Powered Device (PD), the TPS2371 performs all detection, class−ification, inrush current limiting, and switch FET control that is necessary for compatibility with Legacy/IEEE 802.3af Standard. The TPS2371 incorporates precision UVLO thresholds and hysteresis as well as a UVLO off-time delay to enable Legacy IEEE802.3af PoE compatibilty. An internal 0.3-Ω FET provides maximum power delivery. As an additional feature, the TPS2371 interfaces with the enable/soft-start signal of a dc-to-dc converter, eliminating the need to have an accurate UVLO in the dc-to-dc converter.

At low input voltages (1.8 V to 10 V), the TPS2371 draws less than 12 μA, allowing accurate sensing of the external 24.9-kΩ discovery resistor. At input voltages between 15 V and 20 V, an external resistor sets the level of current to be drawn during classification mode. TPS2371 is compatible with current as well as voltage measurement schemes for classification. Above 20-V input, the classification current is shut off, reducing internal power dissipation.

SIMPLIFIED APPLICATION DIAGRAM



Bluetooth is a trademark of the Bluetooth SIG, Inc.

DESCRIPTION (continued)

The TPS2371 drives an internal low-side FET for control of the return side of the power path. The internal FET is turned on when the input voltage reaches 36 V and above. When the input voltage decreases, the FET remains on until the input voltage drops to below 30 V.

During initial turn-on of the switch (inrush mode), an external resistor is used to program the inrush current, allowing a wide range of capacitor values to be used at the load. According to IEEE 802.3af specification, inrush current of 400 mA is allowed only for 50 ms, limiting the load capacitor to approximately 180 µF. A programmable inrush current limit removes this limitation, allowing a larger capacitor to be used with a lower inrush current limit.

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range unless otherwise noted (2)

		TPS2371	UNIT
Input voltage range, wrt V_{EE}	ILIM, DELAY	4	V
	CLASS	12	
	DET, RTN, EN_DC, VDD	68	
Operating junction temperature range, T_J		−55 to 150	°C
Storage temperature, T_{stg}		−65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		300	°C

(2) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

	MIN	NOM	MAX	UNIT
Input voltage, V_I		48	57	V
Operating junction temperature, T_J	0		70	°C

DISSIPATION RATINGS(3)(4)

PACKAGE	THERMAL IMPEDANCE JUNCTION-TO-AMBIENT	T_A < 25°C POWER RATING	T_A = 25°C DERATING FACTOR	T_A = 70°C POWER RATING
8-Pin Plastic TSSOP (PW)	258.5°C/W	464 mW	3.9 mW/°C	290 mW
8-Pin Plastic SOIC (D)	176.0°C/W	682 mW	5.7 mW/°C	426 mW

(3) Test board conditions:
1. 3” x 3”, 4 layers, thickness: 0.062”
2. 1.5 oz. copper traces located on the top of the PCB
3. 1.5 oz. copper ground plane on the bottom of the PCB
4. 0.5 oz. copper ground planes on the 2 internal layers
5. 12 thermal vias (see “Recommended Land Pattern” in applications section of this data sheet)

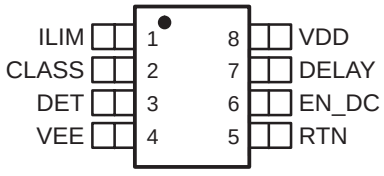
(4) Maximum power dissipation may be limited by over current protection.

ELECTRICAL CHARACTERISTICS

V_{DD} = 48 V; T_A = 0°C to 70°C; all voltages and currents are with respect to VEE; (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
	Offset current	VDD = 1.8 V, DET = OPEN			3	µA
I_{DD}	Sleep current	1.8 V ≤ VDD < 10 V, DET = OPEN		5	12	µA
I_{DET}	Detection load current	R_{DET} = 24.9 kΩ, VDD = 1.8 V	70	73	76	µA
		R_{DET} = 24.9 kΩ, VDD = 9.5 V	380	390	400	µA
	Classification current threshold	Turn on	10.0	12.5	14.0	V
		Turn off	21.5	22.5	23.5	V
	VDD current class 0	0.44 W ≤ P_{PoE} ≤ 12.95 W, 15 V ≤ VDD ≤ 20 V, R_{CLASS} = 4.42 kΩ	2.2	2.5	2.8	mA
	VDD current class 1	0.44 W ≤ P_{PoE} ≤ 3.84 W, 15 V ≤ VDD ≤ 20 V, R_{CLASS} = 953 Ω	10.4	10.8	11.5	mA
	VDD current class 2	3.84 W ≤ P_{PoE} ≤ 6.49 W, 15 V ≤ VDD ≤ 20 V, R_{CLASS} = 549 Ω	18.1	18.6	19.5	mA
	VDD current class 3	6.49 W ≤ P_{PoE} ≤ 12.95 W, 15 V ≤ VDD ≤ 20 V, R_{CLASS} = 357 Ω	27.7	28.4	29.9	mA
	VDD current class 4	Reserved for future use, 15 V ≤ VDD ≤ 20 V, R_{CLASS} = 255 Ω	38.5	39.6	42.0	mA
	VDD quiescent current	30 V ≤ VDD ≤ 57 V, R_{CLASS} = 255 Ω		500	800	µA
	Input UVLO threshold	Turn on	33.9	35.0	36.1	V
		Turn off	29.5	30.5	31.5	V
	UVLO hysteresis		4.3	4.5		V
	UVLO off-time delay	C_{DELAY} = 180 nF		18		ms
	EN_DC sink current		40	80	200	µA
	RTN threshold for EN_DC		1.2	1.5	1.8	V
	DMOS $R_{DS(on)}$	I_{RTN} = 200 mA	0.15	0.30	0.60	Ω
	Full load current limit	V_{RTN} < 1.5 V	405	455	505	mA
	ILIM current limit programming	R_{LIM} = 125 kΩ, V_{RTN} > 1.5 V during startup	180	250	300	mA
	Thermal shutdown temperature			144		°C
	Thermal shutdown hysteresis			20		°C

D OR PW PACKAGE
(TOP VIEW)



ORDERING INFORMATION

T_A	PACKAGE(1)	PART NUMBER
0°C to 70°C	Plastic TSSOP (PW)	TPS2371PW
	Plastic SOIC (D)	TPS2371D

(1) The PW and D packages are also available taped and reeled. Add an R suffix to the device type (i.e., TPS2371PWR).

TERMINAL FUNCTIONS

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
CLASS	2	O	Sets classification level with a single resistor to VEE. A precision voltage of 10.0 V is applied to this pin during classification. R_{CLASS} values listed in Table 1.
DELAY(2)	7	I	UVLO turn-off delay programming. Connect a capacitor between VCC and this pin to program the UVLO turn-off delay.
DET	3	O	Connect the 24.9kΩ detection resistor (R_{DET}) between this pin and VDD.
EN_DC	6	O	Ties to dc-to-dc converter's shutdown or soft-start pin. Sinks 80μA until the load capacitor is fully charged.
ILIM(1)	1	O	Sets startup current limit level with a resistor to VEE. If using $C_{DC2DCIN}$ > 180 μF, I_{RUSH} must be less than 400 mA. Extra capacitance on ILIM pin can cause oscillations in the current waveform.
RTN	5	O	Return pin. Connect this pin to input return side of the dc-to-dc converter.
VDD	8	I	Connection to PD input port positive voltage.
VEE	4	I	Input side power return for the controller.

NOTE 1: $I_{INRUSH} = 450\ mA - \left(\frac{25\ k\Omega}{R_{LIM}}\right) \times (1\ A)$

NOTE 2: $T_{DELAY} = \left(\frac{100\ ms}{\mu F}\right) \times C_{DELAY}$

DETAILED PIN DESCRIPTIONS

ILIM (Pin 1)

Inrush current limiting pin. This pin is used to program the inrush current of the device. Due to the low UVLO hysteresis of this device, a 1.0-μF capacitor from this pin to VEE is necessary to allow startup with 20 Ω in series with V_{DD} as required by the IEEE standards. By placing a resistor to VEE from this pin, the inrush current into the load will be limited via the following equation:

$$I_{INRUSH} = 450\ mA - \left(\frac{25\ k\Omega}{R_{LIM}}\right) \times (1\ A) \quad (1)$$

CLASS (Pin 2)

Classification pin. The PD can be optionally classified by adding a resistor from this pin to ground. The resistor specific to each class is given in *Table 1: PoE Classification Resistance Values*.

DET (Pin3)

Detection pin. This pin is used to set up the detection resistance during PD detection. By tying a resistor, R_{DET}, from this pin to VDD, the user sets the detection resistance. It should be noted that the device itself looks like approximately 1 MΩ of resistance in parallel with R_{DET}.

VEE (Pin 4)

Negative supply to the device.

RET (Pin 5)

Negative supply to the load. This pin is the drain side of a FET between the RET pin and the VEE pin, providing hot swap capabilities to the load. When the FET is switched on, there is approximately 300mΩ between this pin and VEE.

DETAILED PIN DESCRIPTIONS (continued)

EN_DC (Pin 6)

Enable pin for the load. This pin is intended to be used with a dc-to-dc coverter with a soft start capacitor. When power is not available to the dc-to-dc converter, this pin sinks 80-μA and hold off the softstart cap on the dc-to-dc converter. Once the voltage across the load is within 1.5 V of its final value, the EN_DC pin stops drawing current and become high impedance, allowing the dc-to-dc to soft start normally.

DELAY (Pin 7)

This pin controls the amount of time that the device ignores an undervoltage condition on VDD. That time is set by the following equation:

$$T_{DELAY} = \left(\frac{100\ ms}{\mu F}\right) \times C_{DELAY} \quad (2)$$

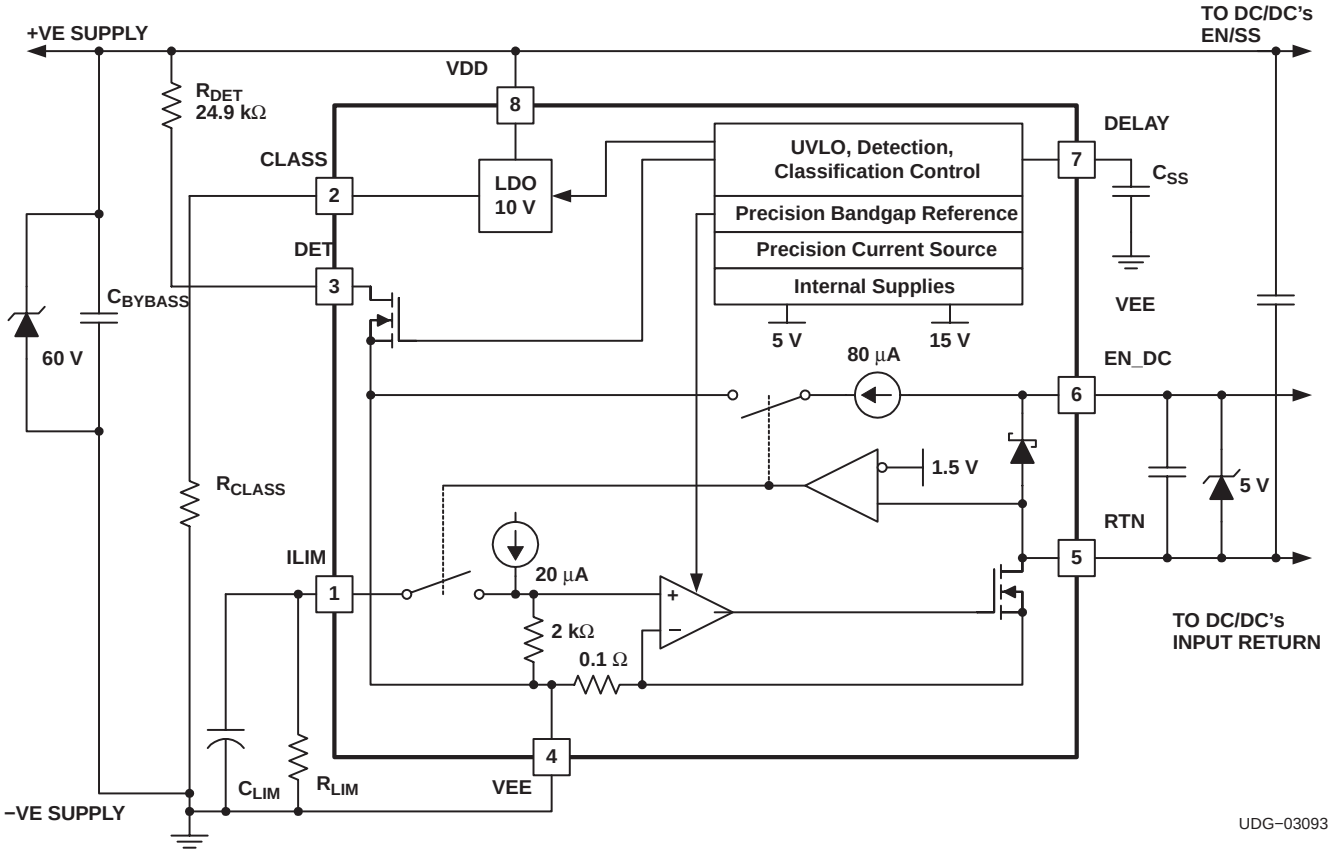
VDD (Pin 8)

Positive supply to the device.

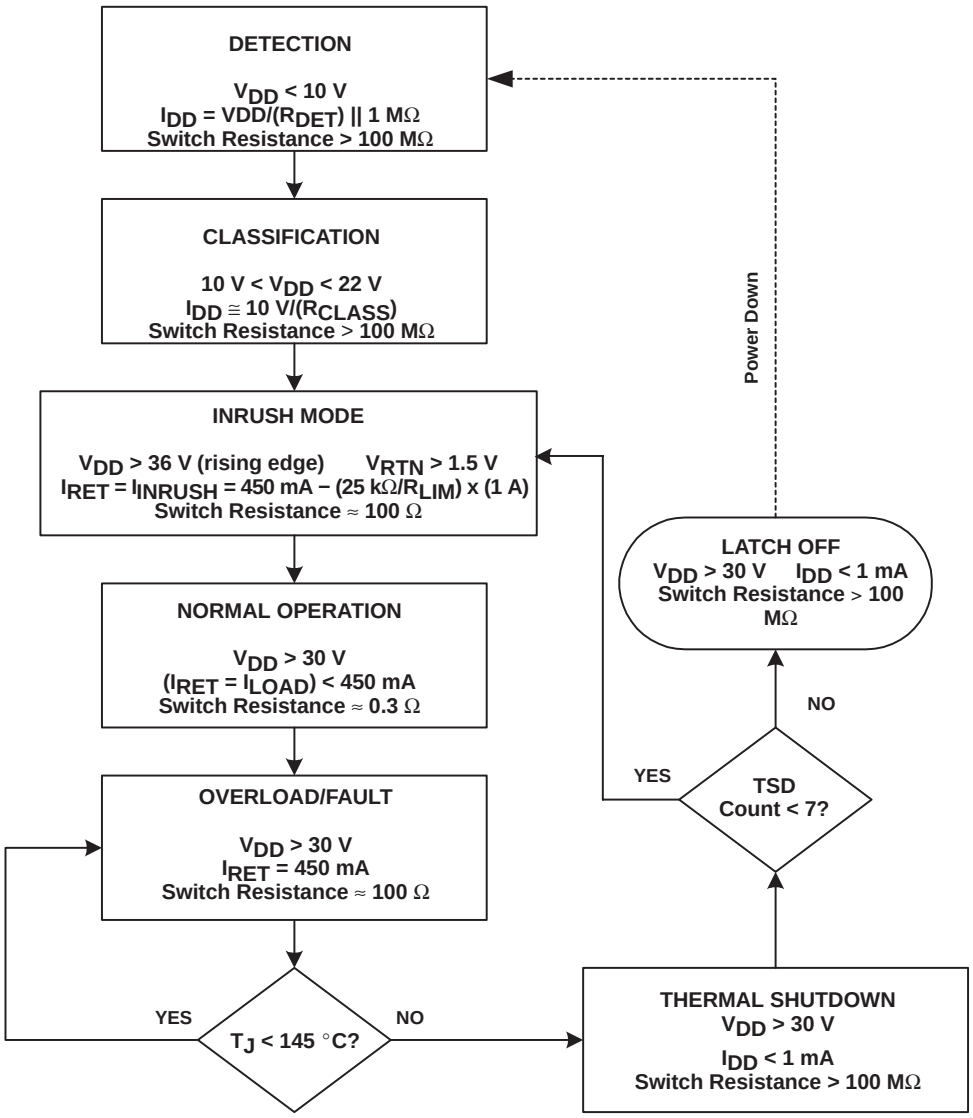
Table 1. PoE Classification Resistance Values

CLASS	RESISTANCE (R_{CLASS}) VALUE (Ω)	POWERED DEVICES (PDs) Power (W)	CLASSIFICATION CURRENT (mA)
0	4420	0.44 − 12.95	2.5
1	953	0.44 − 3.84	10.8
2	549	3.84 − 6.49	18.6
3	357	6.49 − 12.95	28.4
4	255	reserved for future use	39.6

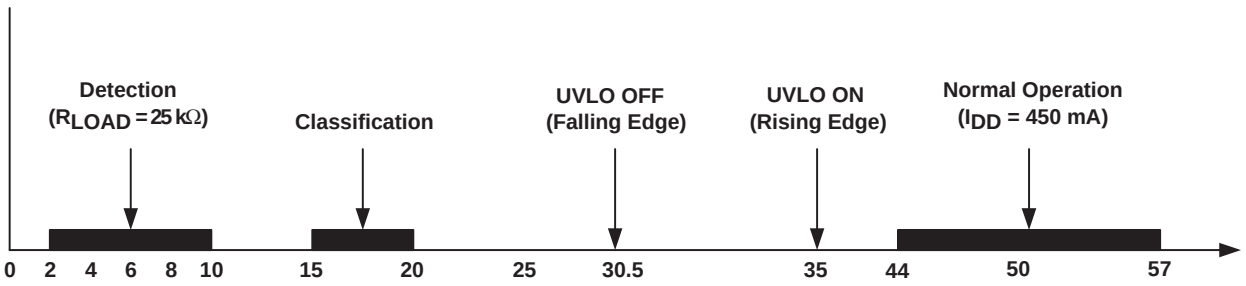
INTERNAL BLOCK DIAGRAM



STATE DIAGRAM



MACHINE STATE



APPLICATION INFORMATION

OVERVIEW

With the addition of power via media dependent interface (MDI) to the IEEE 802.3af Standard, all data terminal equipment (DTE) now has the option to receive power over existing cabling that is used for data transmission. The IEEE 802.3af Standard defines the requirements associated with providing and receiving power over the existing cabling. The power sourcing equipment (PSE) provides the power on the cable and the powered device (PD) receives the power. As part of the IEEE 802.3af Standard, the interface between the PSE and PD is defined as it relates to the detection and classification protocol.

POWER SOURCING EQUIPMENT DETECTION OF A POWERED DEVICE

A powered device (PD) draws power or requests power by participating in a PD detection algorithm. This algorithm requires the power sourcing equipment (PSE) to probe the link looking for a valid PD. The PSE probes the link by sending out a voltage between 2.8 V and 10 V across the power lines. A valid PD detects this voltage and places a resistance of between 23.75 kΩ and 26.25kΩ across the power lines. Naturally, the current varies depending on the input voltage. Upon detecting this current, the PSE concludes that a valid PD is connected at the end of the ethernet cable and is requesting power.

If the powered device (PD) is in a state in which it does not accept power, the PD is required to place a resistance above or below the values listed for a valid PD. On the lower end, a range between 12 kΩ and 23.75 kΩ signifies that the PD does not require power. On the higher end, the range is defined to be between 26.25 kΩ and 45 kΩ . Any resistance value less than 12 kΩ and greater than 45 kΩ, is interpreted by the PSE as a non-valid PD detection signature.

The TPS2371 participates in the detection algorithm by activating an internal FET, which connects the DET pin of the device to VEE. As a result, any resistance connected between VDD and the DET pin of the TPS2371 is, in effect, across the power lines. This internal FET is active only when input power to the PD is between 2.8 V and 10 V.

POWER SOURCING EQUIPMENT CLASSIFICATION OF A POWERED DEVICE

After the detection phase, the PSE can optionally initiate a classification of the PD. The classification of a PD is used by the PSE to determine the maximum power required by the PD during normal operation. Five different levels of classification are defined by the IEEE 802.3af Standard. These levels are shown in Table 2.

Table 2. Powered Device Classification Levels

CLASS	USAGE	POWER DEVICE POWER (W)		CLASSIFICATION CURRENT (mA)	
		MIN	MAX	MIN	MAX
0	Default	0.44	12.95	0	4
1	Optional	0.44	3.84	9	12
2	Optional	3.84	6.49	17	20
3	Optional	6.49	12.95	26	30
4	Not allowed	reserved for future use		36	44

APPLICATION INFORMATION

Classification of the PD is optionally performed by the PSE only after a valid PD has been detected. To determine PD classification, the PSE increases the voltage across the power lines to between 15.5 V and 20.5 V. The amount of current drawn by the PD determines the classification (see Table 2).

When the input voltage to the TPS2371 is between 14.0 V and 20.5 V, the TPS2371 uses an internal regulator to generate a fixed voltage on the CLASS pin. A resistor connected between the CLASS pin and VEE draws a fixed amount of current and thereby defines the classification level of the PD.

POWER SOURCING EQUIPMENT POWER TO THE POWERED DEVICE

Upon completion of the detection and optional classification phases, the PSE ramps its output voltage above 36 V . Once the UVLO threshold has been reached, the internal FET is turned on. At this point, the PD begins to operate normally and it continues to operate normally as long as the input voltage remains above 30 V. For most PDs, this input voltage is down-converted using an on board dc-to-dc converter to generate the required voltages.

The TPS2371 is designed to apply the PSE output voltage of 36 V to 57 V across the input of the on board dc-to-dc converter. This is accomplished on the TPS2371 by turning on an internal pass FET located across the power return.

Programming the Inrush Current

During the initial turn-on of the pass FET, an inrush current is created from the charging of the capacitance at the input of the dc-to-dc converter. According to the IEEE 802.3af specification, if the input capacitance is less than 180-µF, the PSE limits the inrush current. If the input capacitance is greater than 180-µF, the IEEE 802.3af specification requires the PD to limit the inrush current to less than 400 mA.

In order to satisfy the IEEE 802.3af requirements, the TPS2371 has been designed for a typical current limit of 450 mA. This current limit setting satisfies the normal operation requirements as well as the inrush requirements for a capacitive load of 180-µF or less. If a larger load capacitor is desired, the TPS2371 has been designed with a programmable inrush current limit feature. This feature allows the designer the option of using a capacitor larger than 180-µF. Note that the inrush current feature may also be used to lower voltage drops in the cabling between the PSE and the PD during startup.

The programmable inrush current limit has a range of 50 mA to 449 mA. The limit is set by connecting an external resistor from ILIM (pin 1) to VEE (pin 4) of the TPS2371. Equation (3) shows the calculation for the programmable inrush current limit.

$$I_{INRUSH} = 450\ mA - \left(\frac{25\ k\Omega}{R_{LIM}}\right) \times (1\ A) \quad (3)$$

where R_{LIM} is a value between 63.5 kΩ and 25 MΩ.

APPLICATION INFORMATION

Using EN_DC as a SoftStart or a PowerGood Function

The EN_DC pin is an output intended for use as a soft-start for a dc-to-dc converter. During the initial turn-on of the pass FET, an internal 80-μA current sink is enabled on the EN_DC pin. This internal current sink is removed only after the load capacitance has been charged to within 1.5-V of the supply voltage. By connecting the EN_DC output to the soft start capacitor of a dc-to-dc converter, the internal current sink keeps the dc-to-dc converter off during startup. Once the voltage across the converter has reached within 1.5 V of full voltage, the dc-to-dc converter is allowed to soft start. A 5-V zener diode connected between EN_DC and RTN is required for operation in this architecture.

For operation as a powergood output, the EN_DC requires an external pull-up. A 1-MΩ resistor is recommended. The EN_DC output also requires a clamp to limit the output voltage to within recommended operating levels. A 5-V zener diode connected between EN_DC and RTN (pin 5 of the TPS2371) is recommended. This configuration allows the EN_DC pin to act as an open drain output with which many designers are more familiar.

SURGE SUPPRESSION

As specified in the *Absolute Maximum Ratings* table, the absolute maximum input voltage of the TPS2371 is 68 V. The IEEE 802.3af Power-Over-Ethernet Standard specifies the voltage range of PSE output is between 44 V asd 57 V. This PSE output voltage range would be reduced by cable, connector and other IR drops between the PSE and the TPS2371 in the PD. However, the use of extended cable lengths and transformers in some applications may induce transients in excess of 68 V during a hot plug event. To manage these transient events and keep them from significantly exceeding the application's maximum voltage, a transorb such as the SMAJ54A should be placed between the positive input supply, VDD (pin 8), and the negative input supply, VEE (pin 4). This, combined with a 0.1-μF bypass capacitor in parallel with the transorb helps to protect the TPS2371 from damage caused by transients during hot plug events. The transorb or zener diode should be selected such that it does not zener below the maximum required application voltage of 57 V, but before reaching the 68-V absolute maximum rating. For layout purposes, the 0.1-μF capacitor should be placed as close as possible to the device; the transorb or zener diode should be placed as close to the supply connector as possible. Based on the nature of the PD application, these measures should be considered an implementation requirement.

USE OF BARREL RECTIFIERS

Many applications use barrel rectifiers after the RJ-45 connector in order to be polarity insensitive. Barrel rectifiers in front of the TPS2371 cause the voltages at the device to be lower than the voltages at the RJ-45. The TPS2371 allows for this and is IEEE802.3af compliant during the detection and classification phases. For the detection phase, the device begins detection for voltages as low as 1.3 V across the supply pins. For the optional classification phase, the device is guaranteed to start classification below 14 V across the supply pins. Once classification has been engaged, it becomes latched-in and further voltage drops due to cable resistance and class current does not cause it to switch out of classification. However, in cases where the PSE is operating at minimum class voltage (15.5 V) and there is a 20-Ω, 100-m cable between the PSE and the PD, Class 3 devices may not classify correctly when using barrel rectifiers. Class 3 device designs should include schottky diodes to handle all corner cases or switch to Class 0 devices when using barrel rectifiers.

Thermal Shutdown

In the event of a short circuit or overload condition, the TPS2371 begins to heat up until thermal shutdown is reached. Once thermal shutdown is reached, the internal FET is switched off, removing the load from the supply. After the device has cooled sufficiently, it retries by restarting the internal FET. If the overload or short is not removed, the device cycles thermal shutdown seven times before latching the internal FET off. Once the internal FET is latched off, power needs to be cycled to reset the latch.

APPLICATION INFORMATION

Figure 1 shows an application where 40 V < V_{IN} < 57 V. In this case, the brick supply is greater then 40 V and goes through TPS2371.

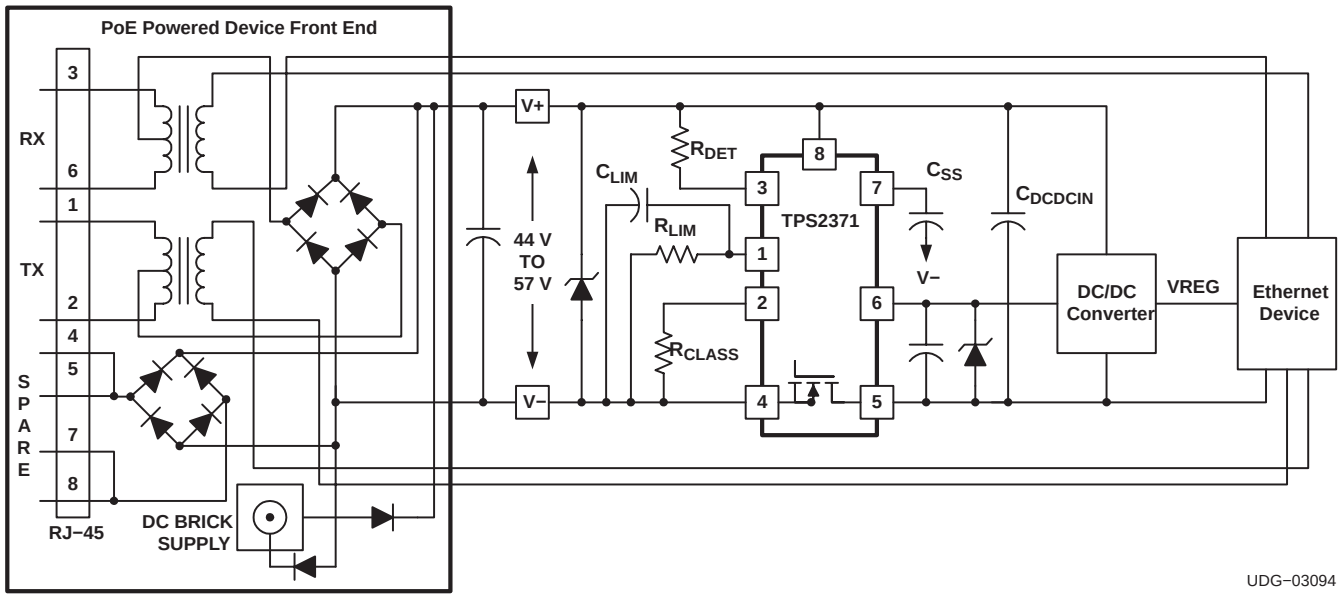


Figure 1. For Applications 40 V < V_{IN} < 57 V.

Figure 2 shows an application where V_{IN} < 36 V. In this application, the brick supply is bypassing the hot swap switch. Consequently, the dc-to-dc converter can operate from any voltage. However, for V_{BRICK} < 23 V, a Class 0 resistor (R_{CLASS} = 4.42 kΩ) is recommended. This minimizes the power dissipation in TPS2371 if V_{BRICK} falls in the classification voltage range (15 V to 20 V). The 80-µA current sink on EN_DC pin is enabled only if VDD > 36 V.

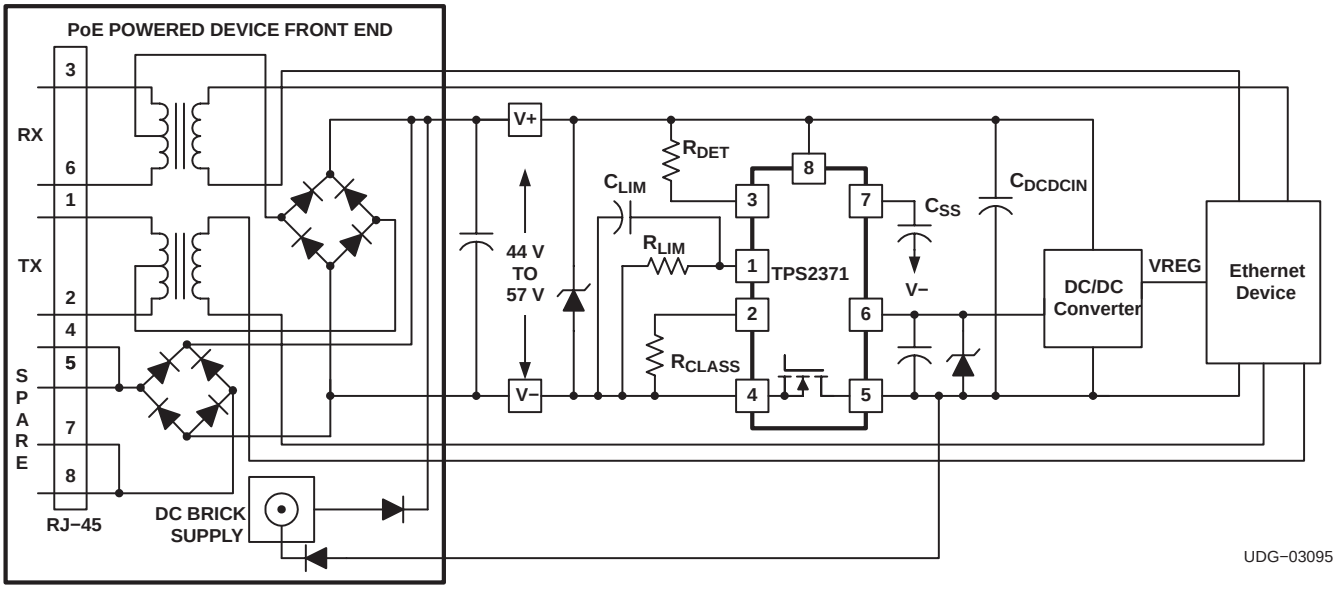


Figure 2. For Applications V_{IN} < 40 V.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPS2371D	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371DG4	NRND	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371DR	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371DRG4	NRND	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371PW	NRND	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371PWG4	NRND	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371PWR	NRND	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	
TPS2371PWRG4	NRND	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2371	

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

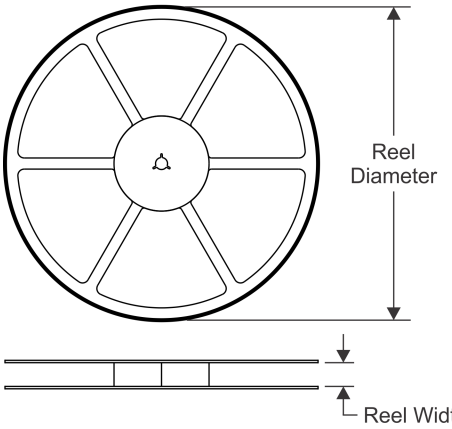
(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

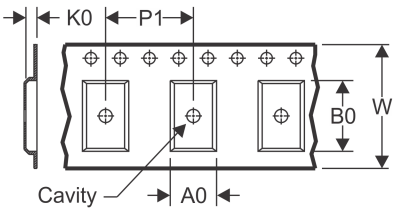
(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

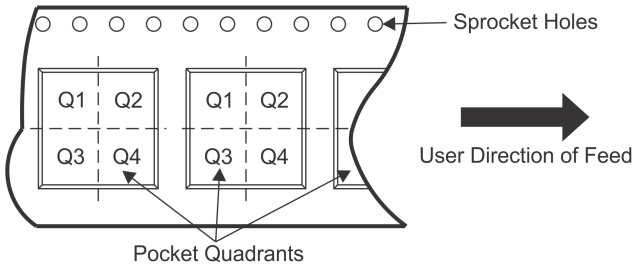


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

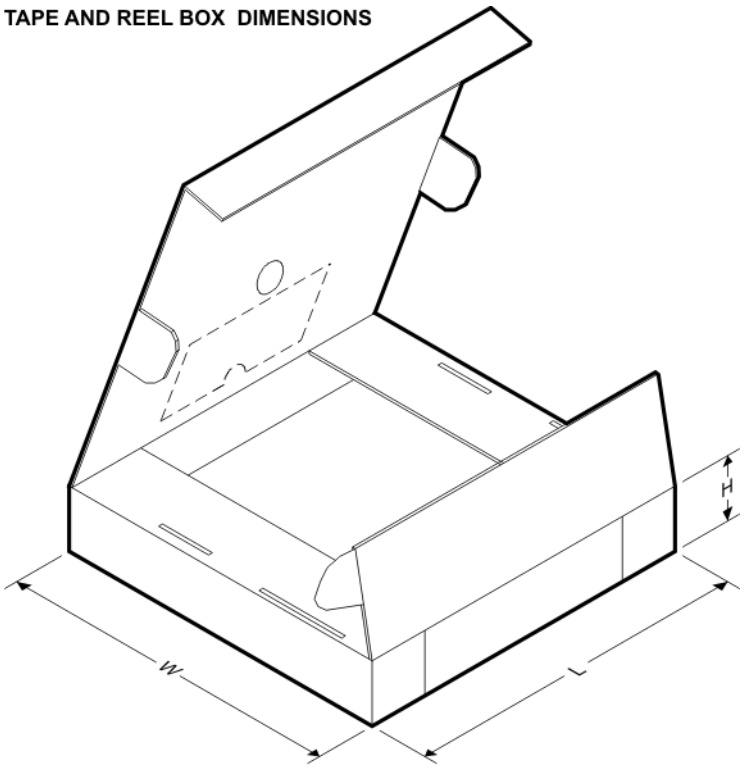
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2371DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2371PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

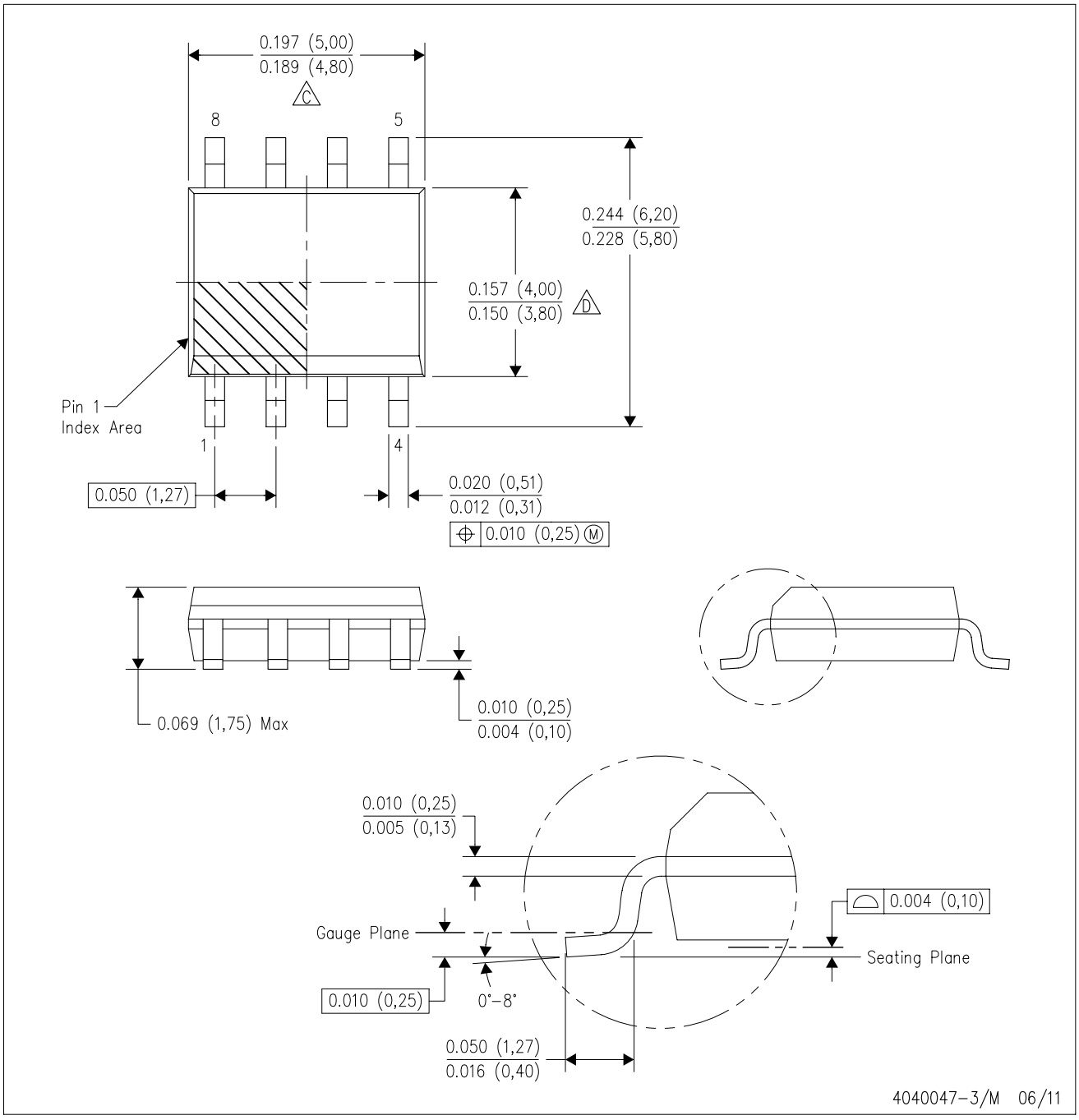
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

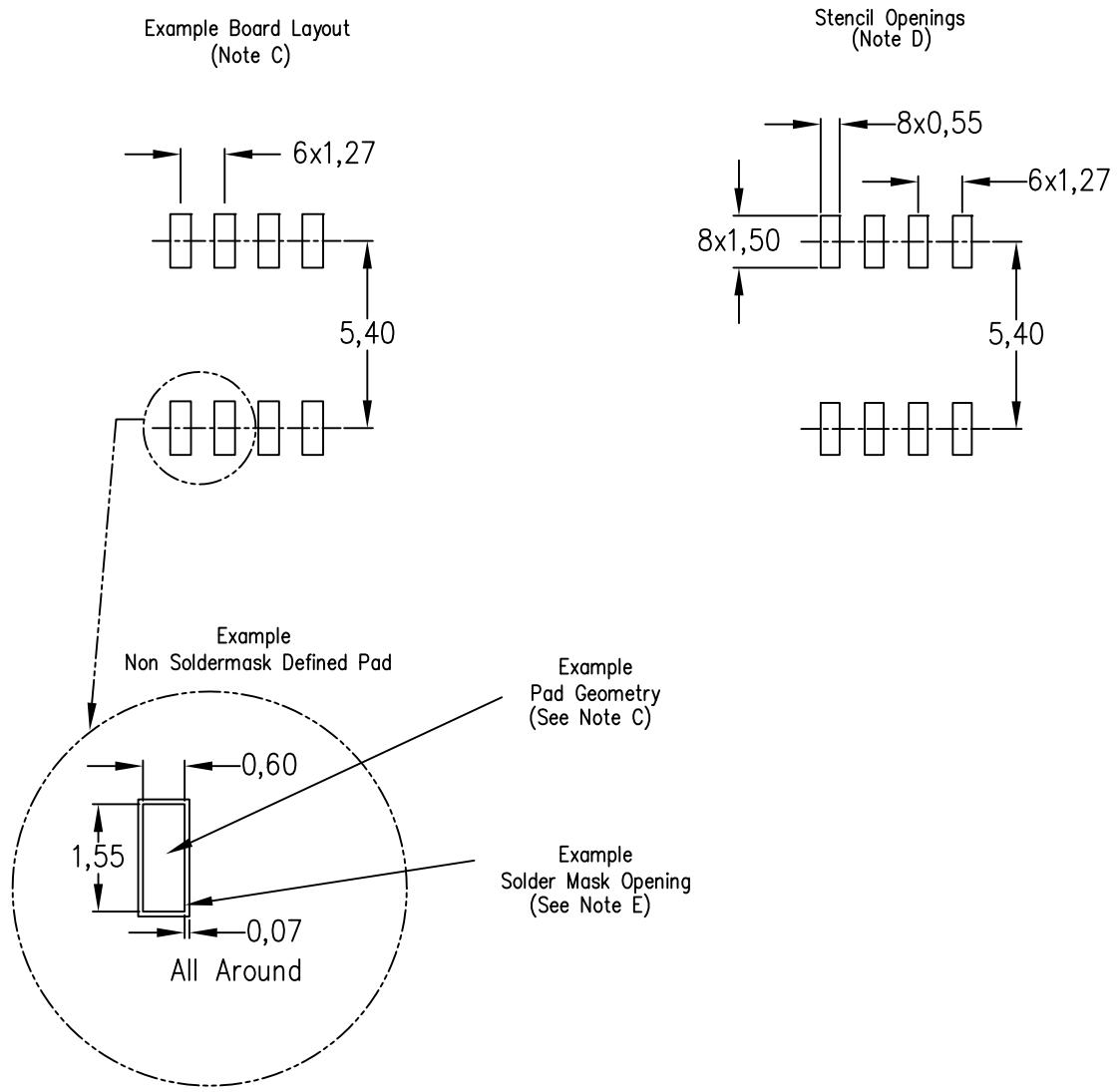
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2371DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2371PWR	TSSOP	PW	8	2000	367.0	367.0	35.0

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



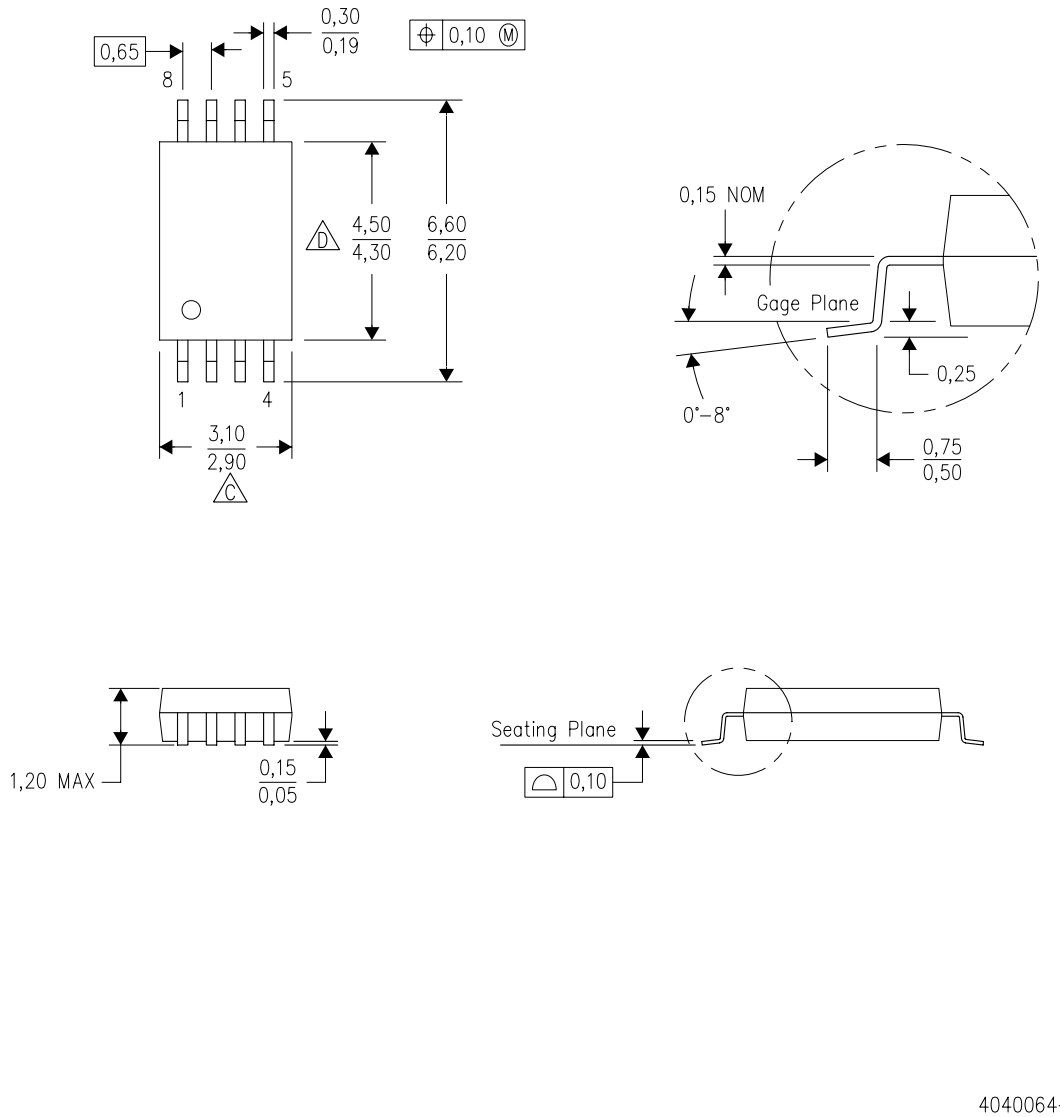
NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R–PDSO–G8) PLASTIC SMALL OUTLINE



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NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

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